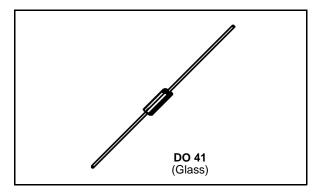


## SMALL SIGNAL SCHOTTKY DIODES



#### DESCRIPTION

Metal to silicon rectifier diodes in glass case featuring very low forward voltage drop and fast recovery time, intended for low voltage switching mode power supply, polarity protection and high frequency circuits.

#### **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit		
I <sub>F(AV)</sub>	Average Forward Current* $T_{amb} = 60 \degree C$		1	А	
I <sub>FSM</sub>	Surge non Repetitive Forward Current	e Forward Current $T_{amb} = 25^{\circ}C$ $t_p = 10ms$ Sinusc		A	
		$\begin{array}{l} T_{amb} = 25^{\circ}C\\ t_{p} = 300\mu s \end{array}$			
T <sub>stg</sub> T <sub>j</sub>	Storage and Junction Temperature Range	- 65 to + 150 - 65 to + 125	°C °C		
TL	Maximum Lead Temperature for Soldering durin from Case	230	°C		

Symbol	Parameter	BYV 10-40	Unit
Vrrm	Repetitive Peak Reverse Voltage	40	V

\* On infinite heatsink with 4mm lead length

#### THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
R <sub>th(j-a)</sub>	Junction-ambient*	110	°C/W

\* On infinite heatsink with 4mm lead length

## ELECTRICAL CHARACTERISTICS

#### STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> *	T <sub>j</sub> = 25°C	$V_{R} = V_{RRM}$			0.5	mA
	T <sub>j</sub> = 100°C				10	
V <sub>F</sub> *	I <sub>F</sub> = 1A	$T_j = 25^{\circ}C$			0.55	V
	I <sub>F</sub> = 3A				0.85	

\* Pulse test:  $t_p \le 300 \mu s \quad \delta < 2\%$ .

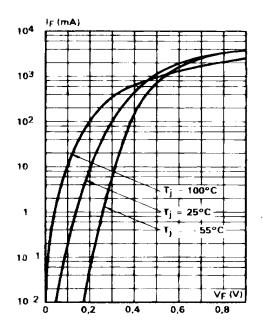
### DYNAMIC CHARACTERISTICS

Symbol	Test Conditions		Тур.	Max.	Unit
С	$T_j = 25^{\circ}C$ $V_R = 0$		220		pF

Forward current flow in a Schottky rectifier is due to majority carrier conduction. So reverse recovery is not affected by stored charge as in conventional PN junction diodes.

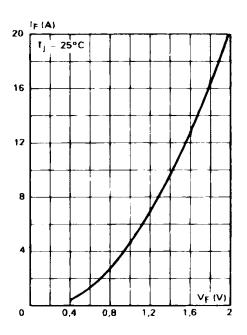
Nevertheless, when the device switches from forward biased condition to reverse blocking state, current is required to charge the depletion capacitance of the diode.

# Fig.1 : Forward current versus forward voltage at low level (typical values).



This current depends only of diode capacitance and external circuit impedance. Satisfactory circuit behaviour analysis may be performed assuming that Schottky rectifier consists of an ideal diode in parallel with a variable capacitance equal to the junction capacitance (see fig. 5 page 4/4).

# Fig.2 : Forward current versus forward voltage at high level (typical values).



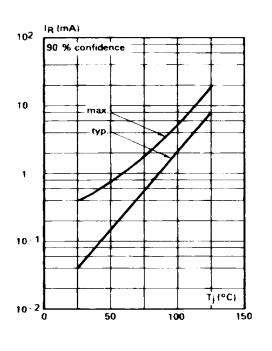


Fig.3 : Reverse current versus junction temperature.

Fig.5 : Capacitance C versus reverse applied voltage  $V_R$  (typical values).

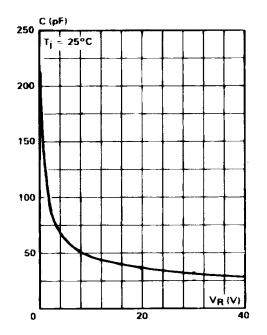


Fig.4 : Reverse current versus  $V_{\mbox{\scriptsize RRM}}$  in per cent.

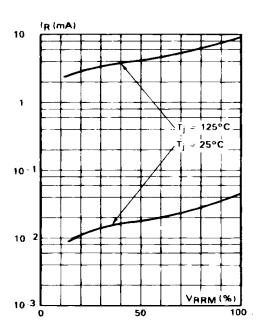
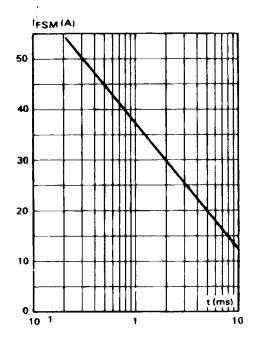
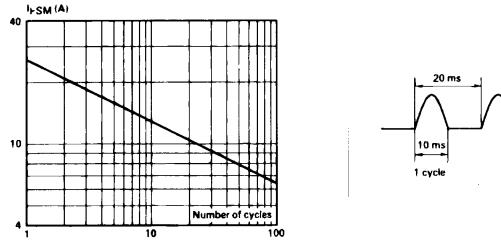


Fig.6 : Surge non repetitive forward current for a rectangular pulse with t  $\leq$  10 ms.



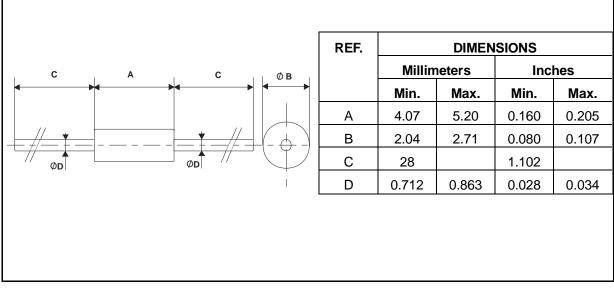
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Figure 7. Surge non repetitive forward current versus number of cycles.



### PACKAGE MECHANICAL DATA

DO 41 Glass



- Marking: clear, ring at cathode end.
- Cooling method : by convection and conduction
- Weight: 0.33g

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